GTM CORPORATION

G3U1117A

1A Low Dropout Positive Adjustable or Fixed-Mode Regulator

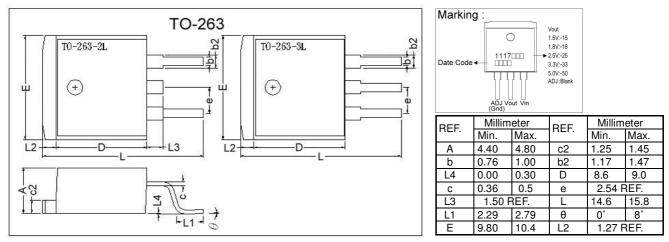
Description

The G3U1117A is a low dropout at positive adjustable or fixed-mode regulator with minimum of 1A output current capability. The product is specifically designed to provide well-regulated supply for low voltage IC applications such as high-speed bus termination and low current 3.3V logic supply. G3U1117A is also well suited for other applications such as VGA cards. G3U1117A is guaranteed to have lower than 1.4V dropout at full load current making it ideal to provide well-regulated outputs of 1.25 to 5.0 with 6.4V to 12V input supply.

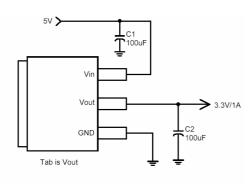
Features

- 1.4Vmaximum dropout full load current
- Fast transient response
- Output current limiting
- Built-in thermal shutdown
- Good noise rejection
- 3-Terminal Adjustable or Fixed 1.5V,1.8V,2.5V,3.3V,5.0V

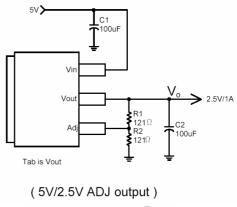
Package Dimensions



Typical Circuit



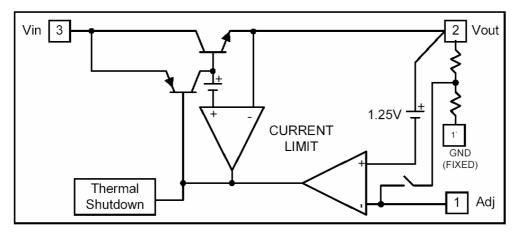
(5V/3.3V fixed output)



Note:
$$V_o = V_{REF} * (1 + \frac{R_2}{R_1})$$

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Block Diagram



Pin Descriptions

Name	I/O	Pin#	Function		
Adj (GND)		1	A resistor divider from this pin to the Vout pin and ground sets the output voltage (Ground only for fixed mode)		
Vout	0	2	The output of the regulator. A minimum of 10uF capacitor must be connected from this pin to ground to insure stability.		
Vin	I	3	The input pin of regulator. Typically a large storage capacitor is connected from this pin to ground to insure that the input voltage does not sag below the minimum dropout voltage during the load transient response. This pin must always be 1.3V higher than Vout in order for the device to regulate properly.		

Absolute Maximum Ratings

Symbol	Parameter	Ratings	Unit	
Vin	DC Supply Voltage	-0.3 to 12	V	
PD	Power Dissipation	Internally Limited		
TST	Storage Temperature	-65 ~ + 150	°C	
TOP	Operating Junction Temperature Range	0 ~ + 150	°C	

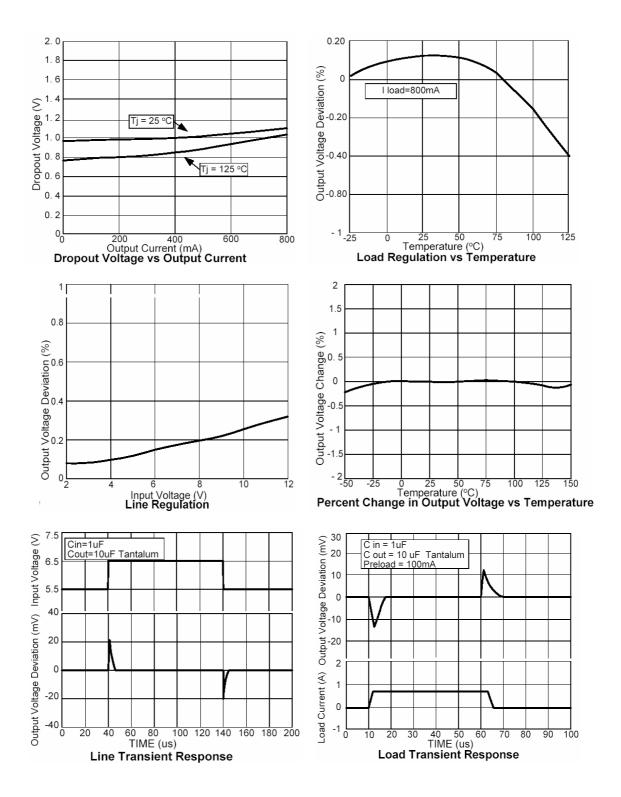
Electrical Characteristics

Parameter		Conditions	MIN	ТҮР	MAX	UNIT
Reference Voltage	G3U1117AADJ	lo=10mA, Tj=25℃, (Vin-Vout)=1.5V	1.225	1.250	1.275	V
	G3U1117A-1.5	lo=10mA, Tj=25℃, 3.0V≤Vin≤12V	1.470	1.500	1.530	V
	G3U1117A-1.8	lo=10mA, Tj=25℃, 3.3V≤Vin≤12V	1.764	1.800	1.836	V
Output Voltage	G3U1117A-2.5	lo=10mA, Tj=25℃, 4.0V≤Vin≤12V	2.450	2.500	2.550	V
	G3U1117A-3.3	lo=10mA, Tj=25℃, 4.8V≤Vin≤12V	3.235	3.300	3.365	V
	G3U1117A-5.0	lo=10mA, Tj=25℃, 6.5V≤Vin≤12V	4.900	5.000	5.100	V
Line Regulation	G3U1117A-XXX	lo=10mA, Vout+1.5V <vin<12v, tj="25℃</td"><td>-</td><td>-</td><td>0.2</td><td>%</td></vin<12v,>	-	-	0.2	%
	G3U1117AADJ	Vin=3.3V, Vadj=0, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>-</td><td>1</td><td>%</td></lo<1a,>	-	-	1	%
	G3U1117A-1.5	Vin=3.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>12</td><td>15</td><td>mV</td></lo<1a,>	-	12	15	mV
Lood Degulation	G3U1117A-1.8	Vin=3.3V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>15</td><td>18</td><td>mV</td></lo<1a,>	-	15	18	mV
Load Regulation	G3U1117A-2.5	Vin=4.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>20</td><td>25</td><td>mV</td></lo<1a,>	-	20	25	mV
	G3U1117A-3.3	Vin=5.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25°C"><td>-</td><td>26</td><td>33</td><td>mV</td></lo<1a,>	-	26	33	mV
	G3U1117A-5.0	Vin=8.0V, 0mA <lo<1a, (note="" 1,2)<="" td="" tj="25℃"><td>-</td><td>40</td><td>50</td><td>mV</td></lo<1a,>	-	40	50	mV
Dropout Voltage (VIN-VOUT)	G3U1117A-XXX	lo=1A, (ΔVout=0.1% Vout)	-	1.3	1.4	V
Current Limit	G3U1117A-XXX	Vin-Vout=5V	1.1	-	-	A
Minimum Load Current	Adjustable model	Vin=5V	-	5	10	mA
Adjust Pin Current	Adjustable model	Vin=12V, Io=10mA	-	50	100	uA
Quiescent Current	fixed model	Vin=12V, Io=0mA	-	-	12	mA
Thermal Regulation	Regulation TA=25°C,30ms pulse		-	0.008	0.04	%/W
Dinala Dejection	F=120HZ,Cout=25uF Tantalum, Iout=1A				•	
Ripple Rejection	G3U1117A-XXX	VIN=VOUT+3V	-	60	70	dB
Temperature Stability	lo=10mA		-	0.5	-	%
θJA Thermal Resistance Junction-to-Ambient(No heat sink ;No air flow)			-	91	-	°C/W
θJC Thermal Resistance Junction-to-Case Control Circuitry/Power Transistor		Power Transistor	-	10	-	°C/W

Note 1: See thermal regulation specifications for changes in output voltage due to heating effects. Line and load regulation are measured at a constant junction Temperature by low duty cycle pulse testing. Load regulation is measured at the output lead =1/18" from the package.

Note 2: Line and load regulation are guaranteed up to the maximum power dissipation of 15W. Power dissipation is determined by the difference in input and output and the output current. Guaranteed maximum power dissipation will not be available over the full input/output range.

Characteristics Curve



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